Product data sheet

# 1. General description

Dual ultrafast power diode in a SOT226A (I2PAK) low-profile plastic package.

### 2. Features and benefits

- · High reverse voltage surge capability
- High thermal cycling performance
- Low thermal resistance
- Soft recovery characteristic minimizes power consuming oscillations
- Very low on-state loss

## 3. Applications

• Output rectifiers in high-frequency switched-mode power supplies

## 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_R$	reverse voltage	DC	-	-	200	V
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; SIN; per diode	-	-	150	Α
		$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; SIN; per diode	-	-	160	А
Static chara	acteristics					
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 15 A; T <sub>j</sub> = 150 °C; <u>Fig. 4</u>	-	0.78	0.85	V
		I <sub>F</sub> = 15 A; T <sub>j</sub> = 25 °C; <u>Fig. 4</u>	-	0.95	1.05	V
		I <sub>F</sub> = 30 A; T <sub>j</sub> = 25 °C; <u>Fig. 4</u>	-	1	1.2	V
Dynamic ch	aracteristics					
t <sub>rr</sub>	reverse recovery time	$I_F$ = 1 A; $V_R$ = 30 V; $dI_F/dt$ = 100 A/ $\mu$ s; $T_j$ = 25 °C; ramp recovery; Fig. 5	-	20	28	ns

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# **5. Pinning information**

### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode 1		A1   A2
2	K	cathode		A1 [ N ] A2
3	A2	anode 2	0	K sym125
mb	К	mounting base; connected to cathode	1 2 3	
			I2PAK (SOT226A)	

# 6. Ordering information

**Table 3. Ordering information** 

Type number	Package	Package				
	Name	Description	Version			
BYV42G-200	I2PAK	plastic single-ended package (I2PAK); TO-262	SOT226A			

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# 7. Limiting values

#### **Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{RRM}$	repetitive peak reverse voltage		-	200	V
$V_{RWM}$	crest working reverse voltage		-	200	V
$V_R$	reverse voltage	DC	-	200	V
I <sub>O(AV)</sub>	average output current	$\delta$ = 0.5; T <sub>mb</sub> ≤ 104 °C; SQW; both diodes conducting; <u>Fig. 1</u> ; <u>Fig. 2</u>	-	30	А
I <sub>FRM</sub>	repetitive peak forward current	$\delta$ = 0.5; $t_p$ = 25 $\mu$ s; $T_{mb} \le$ 104 °C; per diode	-	30	Α
I <sub>FSM</sub>	non-repetitive peak	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; SIN; per diode	-	150	Α
	forward current	$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; SIN; per diode	-	160	Α
I <sub>RRM</sub>	repetitive peak reverse current	$\delta$ = 0.001; $t_p$ = 2 $\mu$ s	-	0.2	А
I <sub>RSM</sub>	non-repetitive peak reverse current	t <sub>p</sub> = 100 μs	-	0.2	А
T <sub>stg</sub>	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C
V <sub>ESD</sub>	electrostatic discharge voltage	HBM; C = 250 pF; R = 1.5 kΩ; all pins	-	8	kV

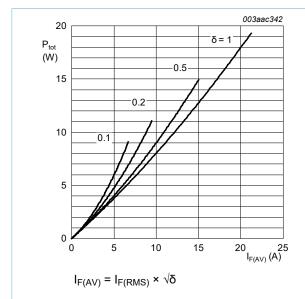
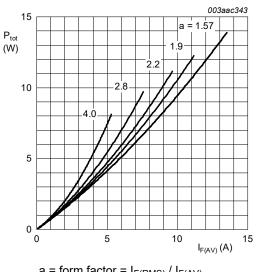


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



 $a = form factor = I_{F(RMS)} / I_{F(AV)}$ 

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

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### 8. Thermal characteristics

**Table 5. Thermal characteristics** 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	with heatsink compound; both diodes conducting	-	-	1.4	K/W
		with heatsink compound; per diode; Fig. 3	-	-	2.4	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient free air	in free air	-	60	-	K/W

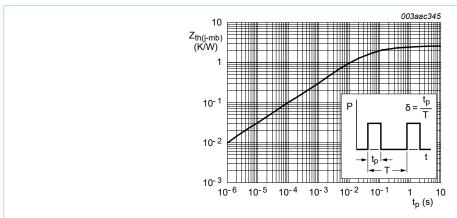


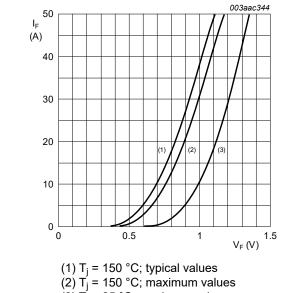
Fig. 3. Transient thermal impedance from junction to mounting base as a function of pulse width

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### 9. Characteristics

#### **Table 6. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 15 A; T <sub>j</sub> = 150 °C; <u>Fig. 4</u>	-	0.78	0.85	V
		I <sub>F</sub> = 15 A; T <sub>j</sub> = 25 °C; <u>Fig. 4</u>	-	0.95	1.05	V
		I <sub>F</sub> = 30 A; T <sub>j</sub> = 25 °C; <u>Fig. 4</u>	-	1	1.2	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 200 V; T <sub>j</sub> = 100 °C	-	0.5	1	mA
		V <sub>R</sub> = 200 V; T <sub>j</sub> = 25 °C	-	10	100	μΑ
Dynamic ch	naracteristics				•	
t <sub>rr</sub>	reverse recovery time	$I_F$ = 1 A; $V_R$ = 30 V; $dI_F/dt$ = 100 A/ $\mu$ s; $T_j$ = 25 °C; ramp recovery; Fig. 5	-	20	28	ns
		I <sub>F</sub> = 0.5 A; I <sub>R</sub> = 1 A; T <sub>j</sub> = 25 °C; step recovery; measured at reverse current = 0.25 A; Fig. 6	-	13	22	ns
Q <sub>r</sub>	recovered charge	$I_F$ = 2 A; $V_R$ = 30 V; $dI_F/dt$ = 20 A/µs; $T_j$ = 25 °C	-	6	15	nC
$V_{FR}$	forward recovery voltage	$I_F = 1 \text{ A}; dI_F/dt = 10 \text{ A/}\mu\text{s}; T_j = 25 °C; Fig. 7$	-	-	1	V



(3) T<sub>i</sub> = 25 °C; maximum values



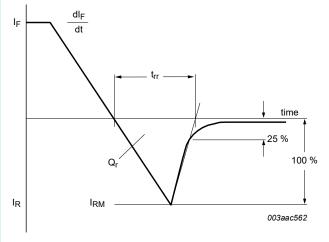
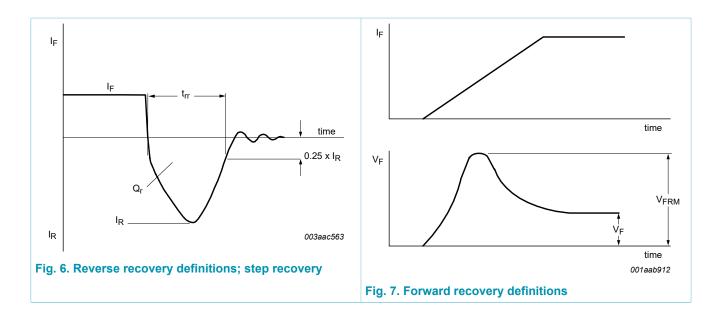


Fig. 5. Reverse recovery definitions; ramp recovery

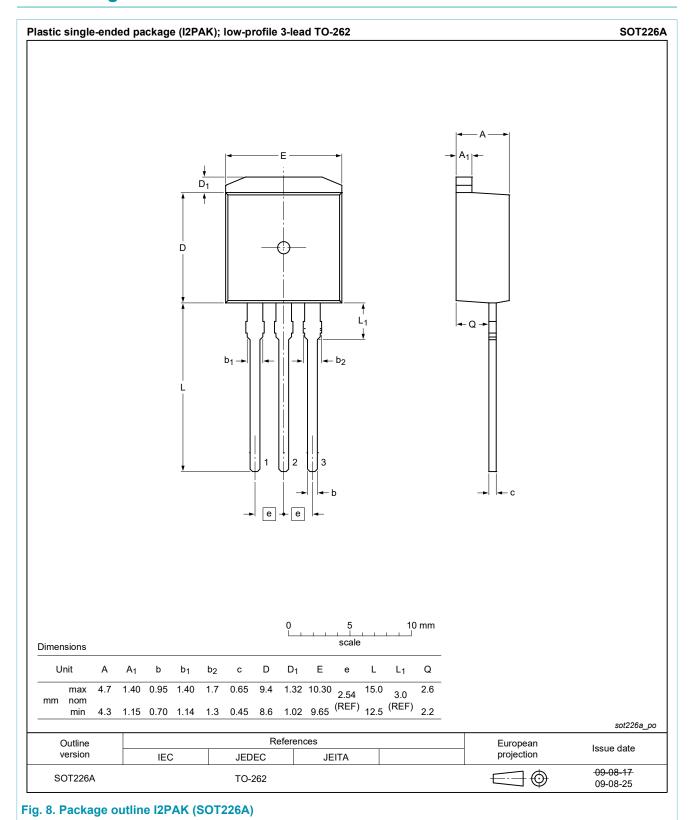
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# 10. Package outline



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#### **Dual ultrafast power diode**

## 11. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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